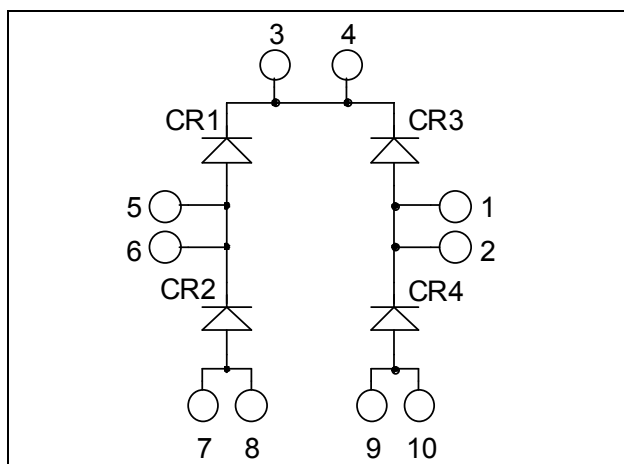


## Fast Diode Full Bridge Power Module

**$V_{RRM} = 600V$**   
 **$I_C = 60A @ T_C = 90^\circ C$**



### Application

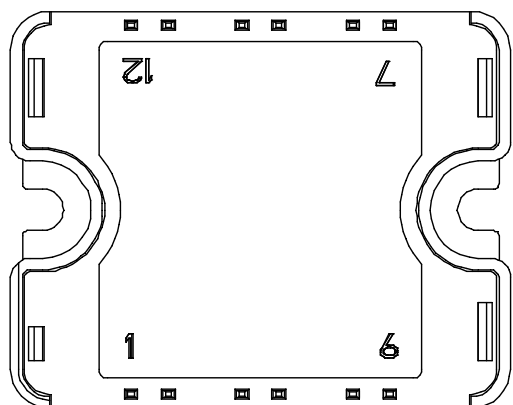
- Uninterruptible Power Supply (UPS)
- Induction heating
- Welding equipment
- High speed rectifiers

### Features

- Ultra fast recovery times
- Soft recovery characteristics
- High blocking voltage
- High current
- Low leakage current
- Very low stray inductance
- High level of integration

### Benefits

- Outstanding performance at high frequency operation
- Low losses
- Low noise switching
- Solderable terminals for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- RoHS Compliant



All multiple inputs and outputs must be shorted together  
 3/4 ; 5/6 ; 7/8 ; 1/2 ; 9/10

### Absolute maximum ratings

| Symbol             | Parameter                               |                  |                       | Max ratings | Unit |
|--------------------|---|------------------|-----------------------|-------------|------|
| V <sub>R</sub>     | Maximum DC reverse Voltage              |                  |                       | 600         | V    |
| V <sub>RRM</sub>   | Maximum Peak Repetitive Reverse Voltage |                  |                       |             |      |
| I <sub>F(AV)</sub> | Maximum Average Forward Current         | Duty cycle = 50% | T <sub>C</sub> = 25°C | 92          | A    |
|                    |   |                  | T <sub>C</sub> = 90°C | 60          |      |
| I <sub>FSM</sub>   | Non-Repetitive Forward Surge Current    | 8.3ms            | T <sub>J</sub> = 45°C | 500         |      |

**CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on [www.microsemi.com](http://www.microsemi.com)

**All ratings @  $T_j = 25^\circ\text{C}$  unless otherwise specified**

**Electrical Characteristics**

| Symbol   | Characteristic                  | Test Conditions                              | Min                       | Typ | Max | Unit          |
|----------|---------------------------------|--|---------------------------|-----|-----|---------------|
| $V_F$    | Diode Forward Voltage           | $I_F = 60\text{A}$                           |                           | 1.7 | 2.3 | V             |
|          |                                 | $I_F = 120\text{A}$                          |                           | 2   |     |               |
|          |                                 | $I_F = 60\text{A}$ $T_j = 125^\circ\text{C}$ |                           | 1.4 |     |               |
| $I_{RM}$ | Maximum Reverse Leakage Current | $V_R = 600\text{V}$                          | $T_j = 25^\circ\text{C}$  |     | 25  | $\mu\text{A}$ |
|          |                                 |  | $T_j = 125^\circ\text{C}$ |     | 500 |               |
| $C_T$    | Junction Capacitance            | $V_R = 200\text{V}$                          |                           | 145 |     | pF            |

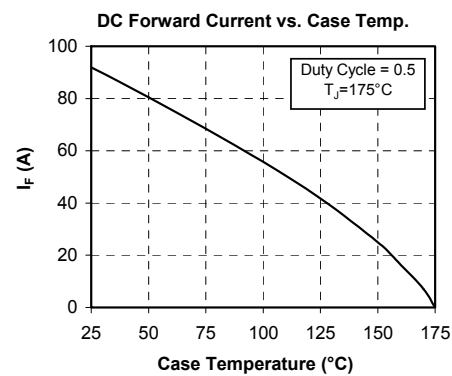
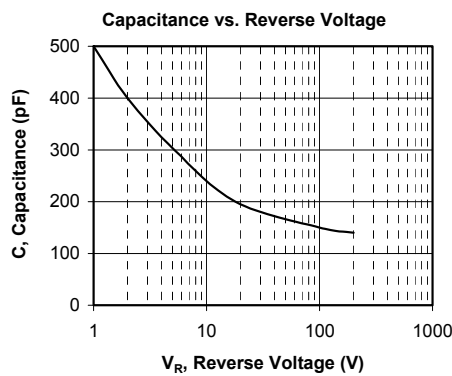
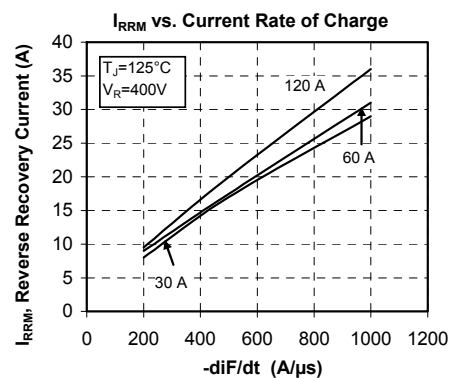
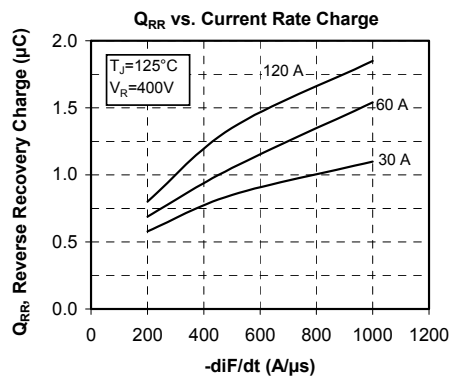
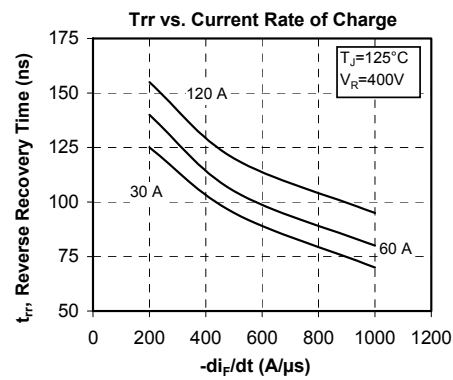
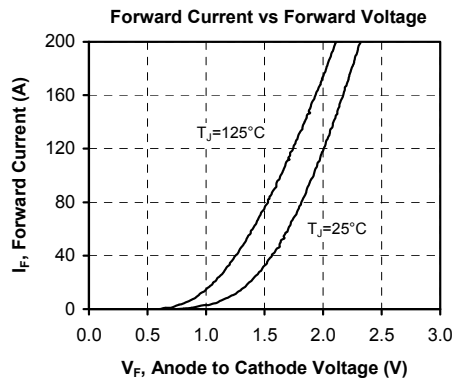
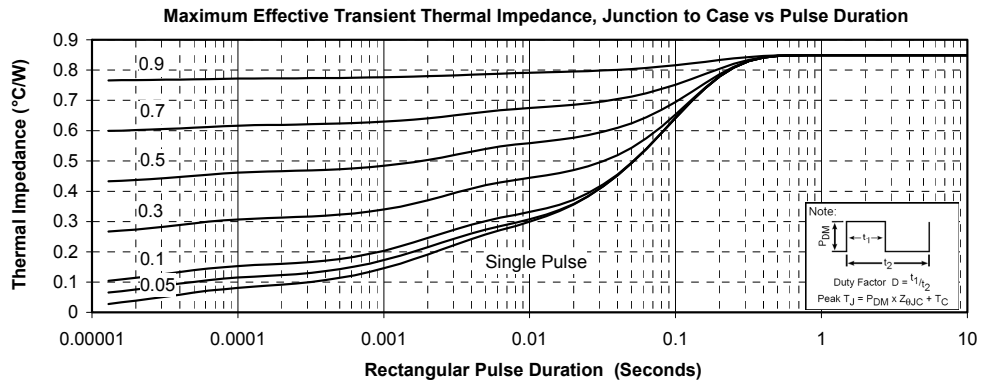
**Dynamic Characteristics**

| Symbol           |                          | Characteristic   | Test Conditions        |  | Min | Typ  | Max | Unit |
|------------------|--------------------------|--|------------------------|--|-----|------|-----|------|
| t <sub>rr</sub>  | Reverse Recovery Time    | I <sub>F</sub> = 60A<br>V <sub>R</sub> = 400V<br>di/dt = 200A/μs | T <sub>j</sub> = 25°C  |  |     | 70   |     | ns   |
|                  |                          |  | T <sub>j</sub> = 125°C |  |     | 140  |     |      |
| Q <sub>rr</sub>  | Reverse Recovery Charge  |  | T <sub>j</sub> = 25°C  |  |     | 100  |     | nC   |
|                  |                          |  | T <sub>j</sub> = 125°C |  |     | 690  |     |      |
| I <sub>RRM</sub> | Reverse Recovery Current |  | T <sub>j</sub> = 25°C  |  |     | 4    |     | A    |
|                  |                          |  | T <sub>j</sub> = 125°C |  |     | 9    |     |      |
| t <sub>rr</sub>  | Reverse Recovery Time    | I <sub>F</sub> = 60A<br>V <sub>R</sub> = 400V<br>di/dt=1000A/μs  | T <sub>j</sub> = 125°C |  |     | 80   |     | ns   |
| Q <sub>rr</sub>  | Reverse Recovery Charge  |  |                        |  |     | 1540 |     | nC   |
| I <sub>RRM</sub> | Reverse Recovery Current |  |                        |  |     | 31   |     | A    |

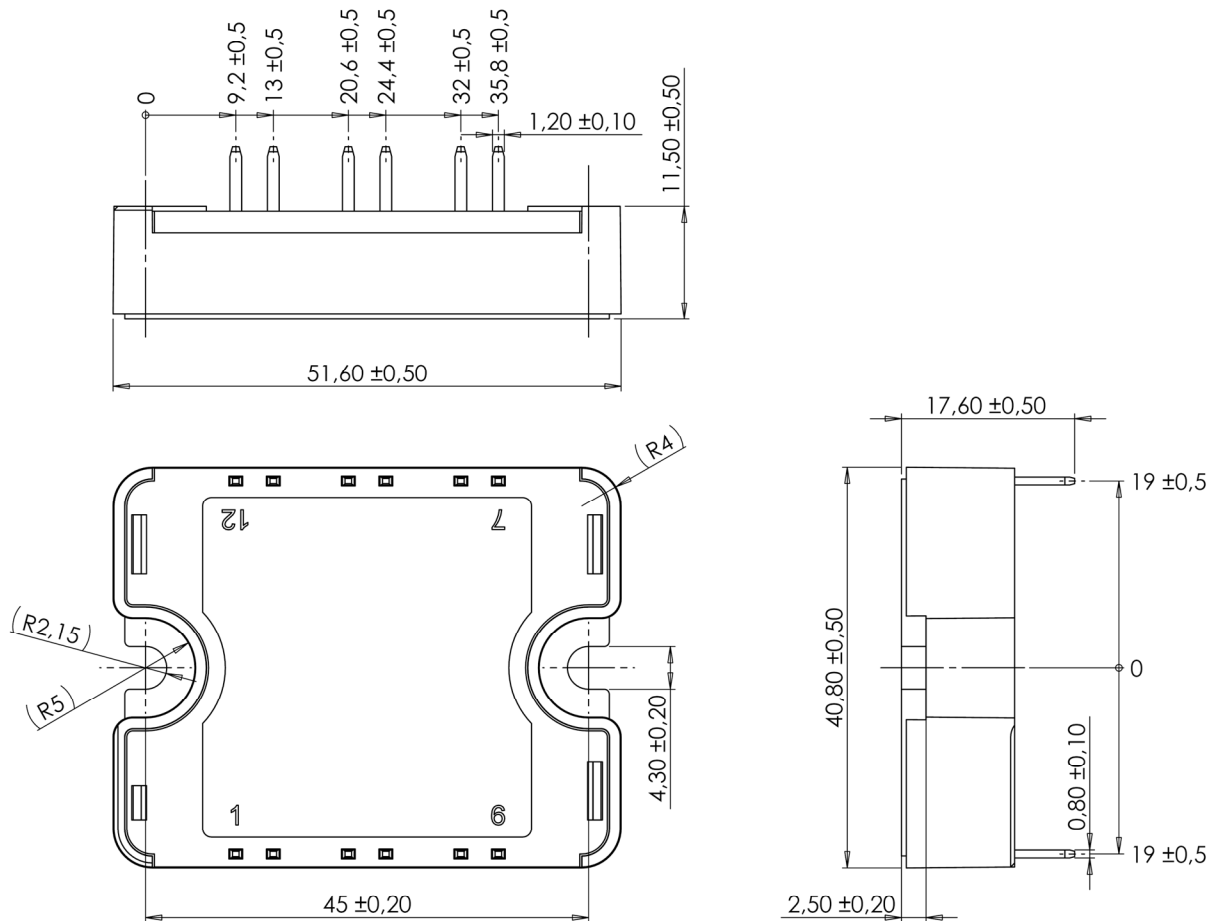
**Thermal and package characteristics**

| Symbol            | Characteristic  |             |    | Min  | Typ | Max  | Unit |
|-------------------|---|-------------|----|------|-----|------|------|
| R <sub>thJC</sub> | Junction to Case Thermal Resistance                           |             |    |      |     | 0.85 | °C/W |
| V <sub>ISOL</sub> | RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz |             |    | 4000 |     |      | V    |
| T <sub>J</sub>    | Operating junction temperature range                          |             |    | -40  |     | 175  | °C   |
| T <sub>STG</sub>  | Storage Temperature Range                                     |             |    | -40  |     | 125  |      |
| T <sub>C</sub>    | Operating Case Temperature                                    |             |    | -40  |     | 100  |      |
| Torque            | Mounting torque   | To heatsink | M4 | 2    |     | 3    | N.m  |
| Wt                | Package Weight  |             |    |      |     | 80   | g    |

## Typical Performance Curve



## SP1 Package outline (dimensions in mm)



See application note 1904 - Mounting Instructions for SP1 Power Modules on [www.microsemi.com](http://www.microsemi.com)

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